Partitioning of input field into different guided modes.

$$E_{in}(y) \xrightarrow[n_2]{n_1} \xrightarrow{n_2} + \underbrace{}_{m_2} + \underbrace{}_{m_2} \xrightarrow{n_2} \xrightarrow{n_$$

For  $a_m$ , use the fact that  $E_m(y)$ 's are orthogonal:  $\int E_m(y)E_n(y)dy = 0$  if  $m \neq n$ (Sturm-Liouville theory)

$$\int E_{in}(y)E_m(y)dy \sim \int \left[\sum_n a_n E_n(y)\right]E_m(y)dy = \sum_n \int a_n E_n(y)E_m(y)dy = \int a_m E_m^2(y)dy$$

$$\therefore a_m = \frac{\int E_{in}(y) E_m(y) dy}{\int E_m^2(y) dy}$$

Dot product between  $E_{in}(y)$  and  $E_m(y)$ Or projection of  $E_{in}(y)$  into basis  $E_m(y)$ 







Issues for practical waveguides

- Precise control of dimension and refractive index
- Low loss at desired  $\boldsymbol{\lambda}$
- Mass production possible
- Integration desirable
- Electrical control of refractive index and/or absorption

Materials used for waveguides

- Silica (SiO<sub>2</sub> with Ge doping)  $\rightarrow$  Optical fiber
- Dielectric materials: LiNbO3 with Ti doping
- Semiconductors: GaAlAs, InGaAsP, Si/SiO<sub>2</sub>



Optical Fiber: Circular dielectric waveguide made of silica (SiO<sub>2</sub>)



What is special about fiber?

- Extremely low loss: 0.2dB/km
- Can be very long: 100's of km







#### LiNbO<sub>3</sub> waveguide (Phase Modulator)



- Used for high-speed optical modulator



Si/SiO<sub>2</sub> waveguide on SOI wafer fabricated with Si technology



What affects the characteristics of Si/SiO2 waveguides?



How to simulate practical waveguides?

- Numerical solutions of the wave equation:
  - MODE Solutions, FDTD (Finite-Difference Time-Domain) Solutions by Lumerical will be used in this class

